



Product data sheet

1. Product profile

1.1 General description

Hyperfast, epitaxial rectifier diode in a SOD113 (2-lead TO-220F) plastic package.

Low thermal resistance

Isolated package

1.2 Features

- Extremely fast switching
- Low reverse recovery current
- Reduces switching loss in associated MOSFET

1.3 Applications

- Half-bridge or full-bridge switched-mode
 Continuous Current Mode (CCM) Power
 power supplies
 Factor Correction (PFC)
- Half-bridge lighting ballasts

1.4 Quick reference data



2. Pinning information

Table 1.	Pinning		
Pin	Description	Simplified outline	Symbol
1	cathode (k)		. 14
2	anode (a)	mb	k ───── ── a <i>001aaa020</i>
mb	mounting base; isolated		

SOD113 (2-lead TO-220F)



3. Ordering information

Table 2. Ordering information						
Type number	Package					
	Name	Description	Version			
BYC15X-600	TO-220F	plastic single-ended package; isolated heatsink mounted; 1 mounting hole; 2-lead TO-220 'full pack'	SOD113			

4. Limiting values

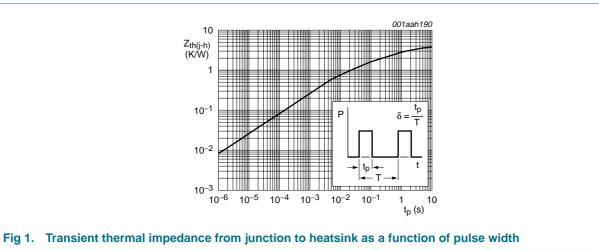
Table 3.Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{RRM}	repetitive peak reverse voltage		-	600	V
V _{RWM}	crest working reverse voltage		-	600	V
V _R	reverse voltage	square waveform; δ = 1.0; $T_h \leq$ 100 $^\circ C$	-	500	V
I _{F(AV)}	average forward current	square waveform; δ = 0.5; T_h \leq 25 $^\circ\text{C}$	-	15	А
I _{FRM}	repetitive peak forward current	square waveform; δ = 0.5; T_h \leq 25 °C; t_p = 25 μs	-	30	А
I _{FSM}	non-repetitive peak forward	t = 10 ms; sinusoidal waveform	-	200	А
	current	t = 8.3 ms; sinusoidal waveform	-	220	А
T _{stg}	storage temperature		-40	+150	°C
Тj	junction temperature		-	150	°C

5. Thermal characteristics

Table 4.	Thermal characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-h)}	thermal resistance from junction to heatsink	with heatsink compound; see <u>Figure 1</u>	-	-	3.6	K/W
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	-	55	-	K/W



6. Isolation characteristics

Table 5. Isolation limiting values and characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{isol(RMS)}	RMS isolation voltage	from all terminals to external heatsink; f = 50 Hz to 60 Hz; sinusoidal waveform; relative humidity \leq 65 %; clean and dust free	-	-	2500	V
C _{isol}	isolation capacitance	from pin 1 (cathode) to external heatsink; f = 1 MHz	-	10	-	pF

 $T_{h} = 25 \circ C$ unless otherwise specified

Characteristics 7.

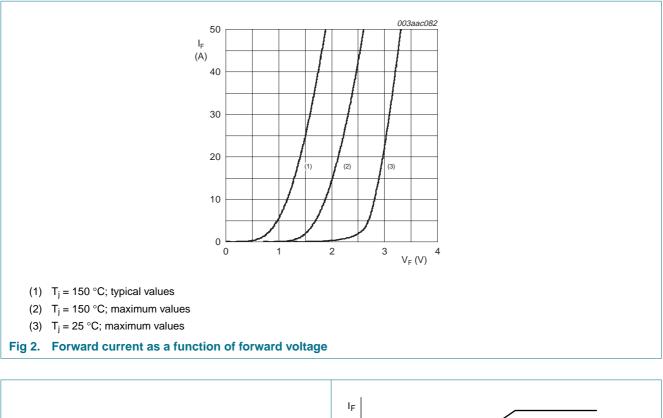
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	racteristics					
V _F	forward voltage	I _F = 15 A; T _j = 150 °C; see <u>Figure 2</u>	-	1.32	2.03	V
		$I_F = 30 \text{ A}; T_j = 150 ^\circ\text{C}; \text{ see } \frac{\text{Figure 2}}{100 ^\circ\text{C}}$	-	1.64	2.34	V
		I _F = 15 A; see <u>Figure 2</u>	-	1.89	2.9	V
I _R	reverse current	V _R = 600 V	-	12	200	μA
		$V_{R} = 500 \text{ V}; \text{ T}_{j} = 100 ^{\circ}\text{C}$	-	1.1	3.0	mA
Dynamic o	haracteristics					
t _{rr}	reverse recovery time	$I_F = 1 \text{ A to } V_R = 30 \text{ V}; \text{ d}_F/\text{d}t = 50 \text{ A}/\mu\text{s};$ see Figure 3	-	35	55	ns
		I_F = 15 A to V_R = 400 V; dI_F/dt = 500 A/µs; see Figure 3				
		T _j = 25 °C	-	19	-	ns
		T _j = 100 °C	-	32	40	ns
I _{RM}	peak reverse recovery current	$I_F = 15 \text{ A to } V_R = 400 \text{ V}; T_j = 125 \text{ °C};$ see Figure 3				
		$dI_F/dt = 50 A/\mu s$	-	3.0	7.5	А
		dl _F /dt = 500 A/µs	-	9.5	12	А
V _{FR}	forward recovery voltage	$I_F = 15 \text{ A}; \text{ dI}_F/\text{dt} = 100 \text{ A}/\mu\text{s}; \text{ see } \frac{\text{Figure 4}}{100 \text{ A}}$	-	8	11	V

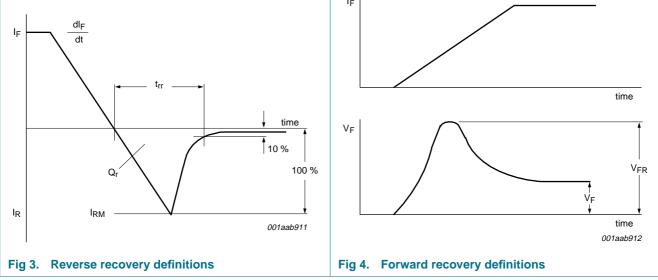
Table 6 Characteristics

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Rectifier diode, hyperfast

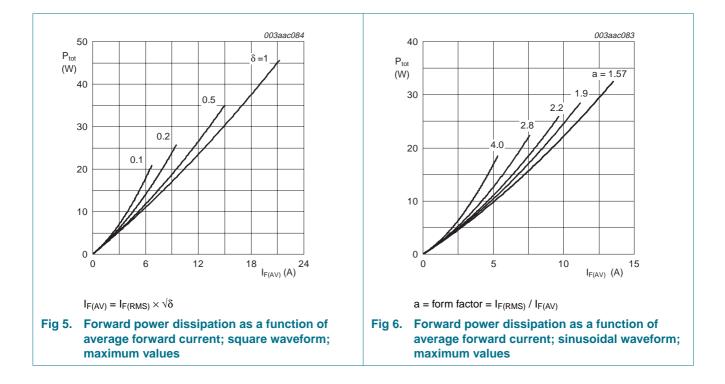




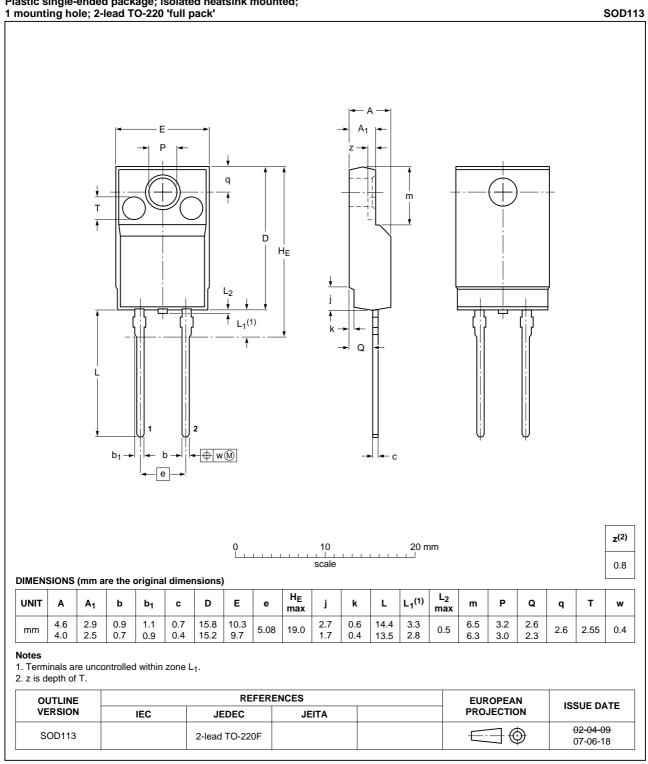
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Rectifier diode, hyperfast



Package outline 8.



Plastic single-ended package; isolated heatsink mounted; 1 mounting hole; 2-lead TO-220 'full pack'

Fig 7. Package outline SOD113 (2-lead TO-220F)



9. Revision history

Table 7. Revision history				
Document ID	Release date	Data sheet status	Change notice	Supersedes
BYC15X-600_1	20071129	Product data sheet	-	-

10. Legal information

10.1 Data sheet status

Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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